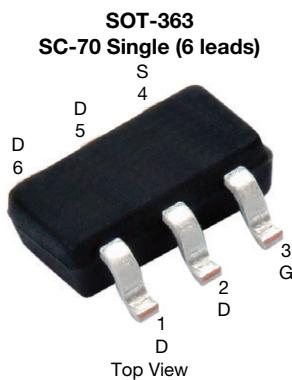


P-Channel 2.5 V (G-S) MOSFET



FEATURES

- TrenchFET® power MOSFET
- Material categorization:
for definitions of compliance please see
www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE
Available

Marking code: OD

PRODUCT SUMMARY	
V_{DS} (V)	-20
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -4.5$ V	0.150
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -3.6$ V	0.175
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -2.5$ V	0.265
Q_g typ. (nC)	2.9
I_D (A)	-1.5
Configuration	Single

ORDERING INFORMATION				
Package	SC-70			
Lead (Pb)-free	Si1403BDL-T1-E3			
Lead (Pb)-free and halogen-free	Si1403BDL-T1-GE3			

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C, unless otherwise noted)				
PARAMETER	SYMBOL	5 s	STEADY STATE	UNIT
Drain-source voltage	V_{DS}	-20	-20	V
Gate-source voltage	V_{GS}	± 12	± 12	
Continuous drain current ($T_J = 150$ °C) ^a	I_D	-1.5	-1.4	A
$T_A = 85$ °C		-1.2	-1.0	
Pulsed drain current	I_{DM}	-5	-5	
Continuous diode current (diode conduction) ^a	I_S	-0.8	-0.8	
Maximum power dissipation ^a	P_D	0.625	0.568	W
$T_A = 85$ °C		0.400	0.295	
Operating junction and storage temperature range	T_J, T_{stg}	-55 to 150		°C

THERMAL RESISTANCE RATINGS					
PARAMETER	SYMBOL	TYPICAL	MAXIMUM	UNIT	
Maximum junction-to-ambient ^a	$t \leq 5$ s	R_{thJA}	165	200	°C/W
	Steady state		180	220	
Maximum junction-to-foot (drain)	Steady state	R_{thJF}	105	130	

Note

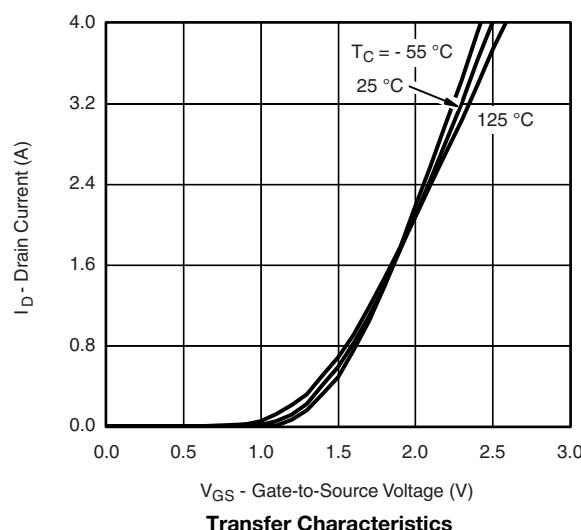
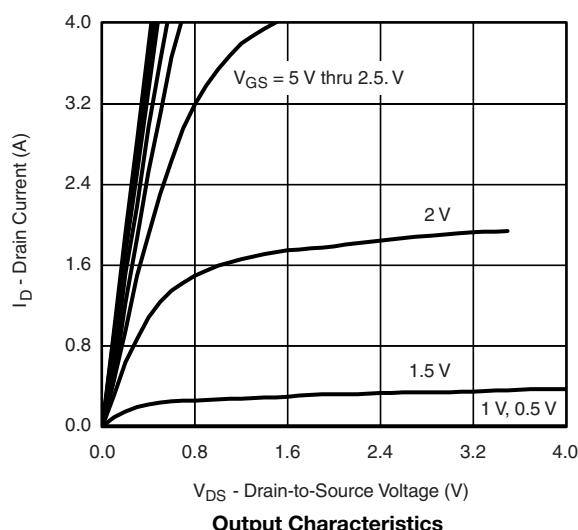
a. Surface mounted on 1" x 1" FR4 board

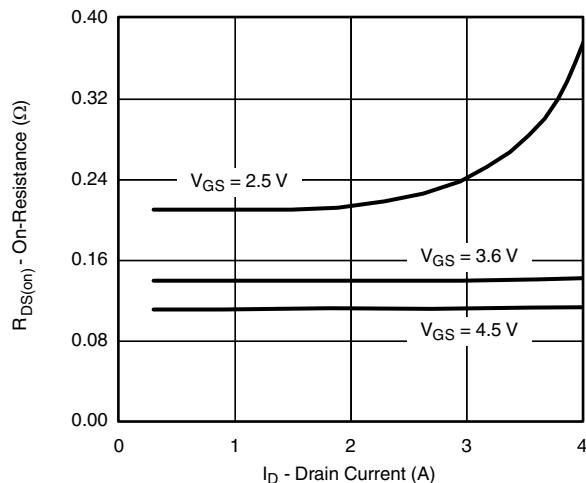
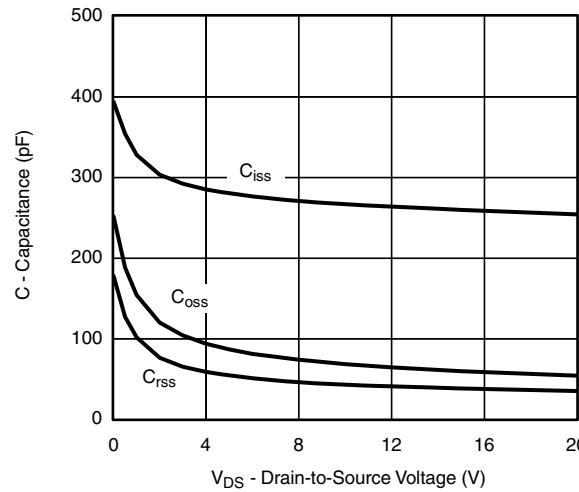
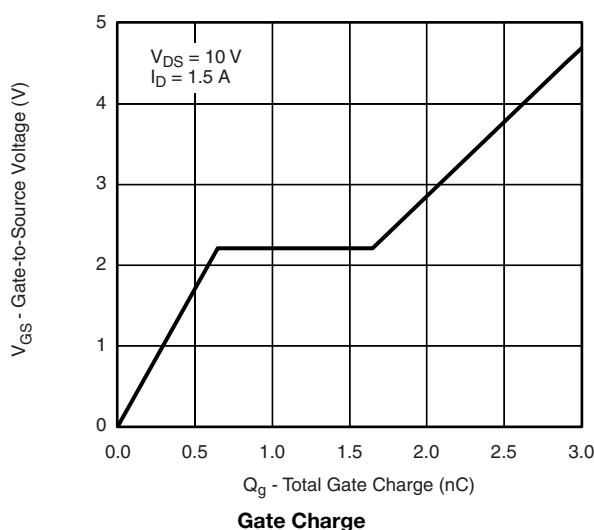
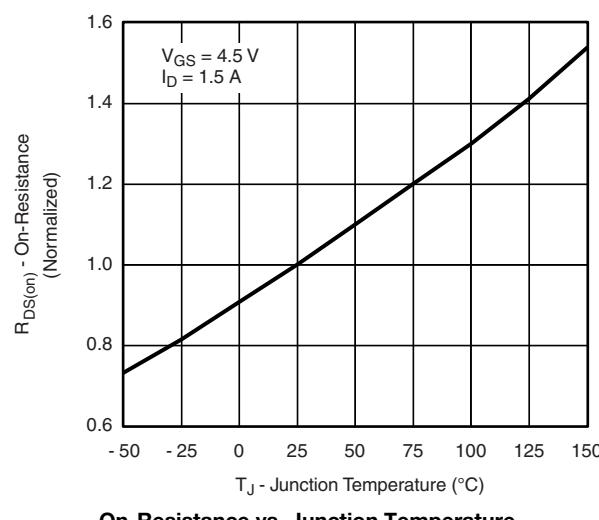
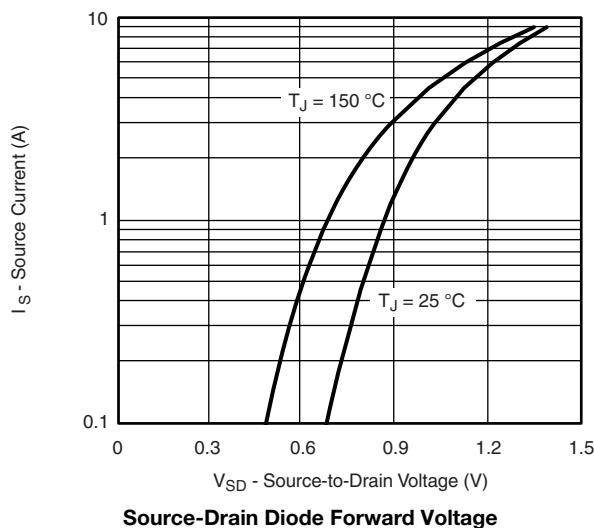
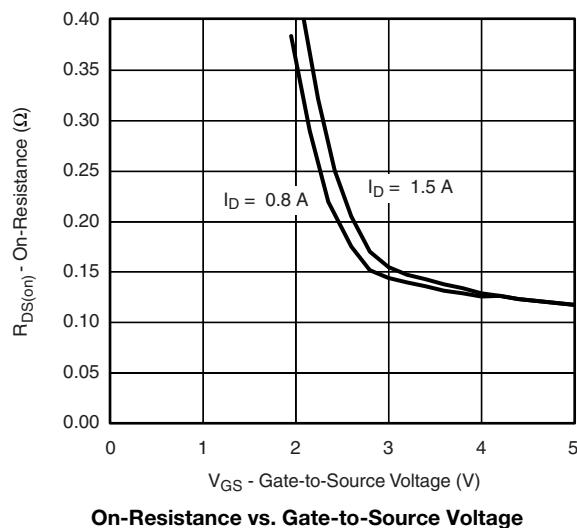
SPECIFICATIONS ($T_J = 25^\circ\text{C}$, unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Gate threshold voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}$, $I_D = -250 \mu\text{A}$	-0.6	-	-1.3	V
Gate leakage	I_{GSS}	$V_{DS} = 0 \text{ V}$, $V_{GS} = \pm 12 \text{ V}$	-	-	± 100	nA
Zero gate voltage drain current	I_{DSS}	$V_{DS} = -20 \text{ V}$, $V_{GS} = 0 \text{ V}$	-	-	-1	μA
		$V_{DS} = -20 \text{ V}$, $V_{GS} = 0 \text{ V}$, $T_J = 85^\circ\text{C}$	-	-	-5	
On-state drain current ^a	$I_{D(\text{on})}$	$V_{DS} = -5 \text{ V}$, $V_{GS} = -4.5 \text{ V}$	-2	-	-	A
Drain-source on-state resistance ^a	$R_{DS(\text{on})}$	$V_{GS} = -4.5 \text{ V}$, $I_D = -1.5 \text{ A}$	-	0.120	0.150	Ω
		$V_{GS} = -3.6 \text{ V}$, $I_D = -1.4 \text{ A}$	-	0.140	0.175	
		$V_{GS} = -2.5 \text{ V}$, $I_D = -0.8 \text{ A}$	-	0.220	0.265	
Forward transconductance ^a	g_{fs}	$V_{DS} = -10 \text{ V}$, $I_D = -1.5 \text{ A}$	-	3.4	-	S
Diode forward voltage ^a	V_{SD}	$I_S = -0.8 \text{ A}$, $V_{GS} = 0 \text{ V}$	-	-0.8	-1.1	V
Dynamic ^b						
Total gate charge	Q_g	$V_{DS} = -10 \text{ V}$, $V_{GS} = -4.5 \text{ V}$, $I_D = -1.5 \text{ A}$	-	2.9	4.5	nC
Gate-source charge	Q_{gs}		-	0.65	-	
Gate-drain charge	Q_{gd}		-	1.0	-	
Gate resistance	R_g	$f = 1 \text{ MHz}$	-	9	-	Ω
Turn-on delay time	$t_{d(\text{on})}$	$V_{DD} = -10 \text{ V}$, $R_L = 10 \Omega$, $I_D \equiv -1 \text{ A}$, $V_{GEN} = -4.5 \text{ V}$, $R_g = 6 \Omega$	-	13	20	ns
Rise time	t_r		-	30	45	
Turn-off delay time	$t_{d(\text{off})}$		-	28	42	
Fall time	t_f		-	13	20	
Source-drain reverse recovery time	t_{rr}		-	12	25	
Body diode reverse recovery charge	Q_{rr}	$I_F = -0.8 \text{ A}$, $dI/dt = 100 \text{ A}/\mu\text{s}$	-	4	8	nC

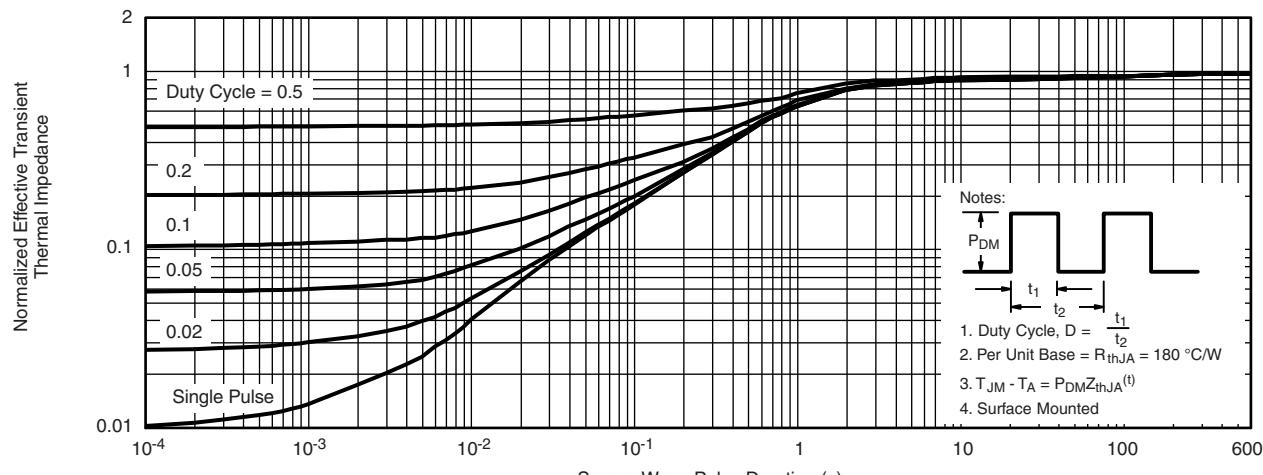
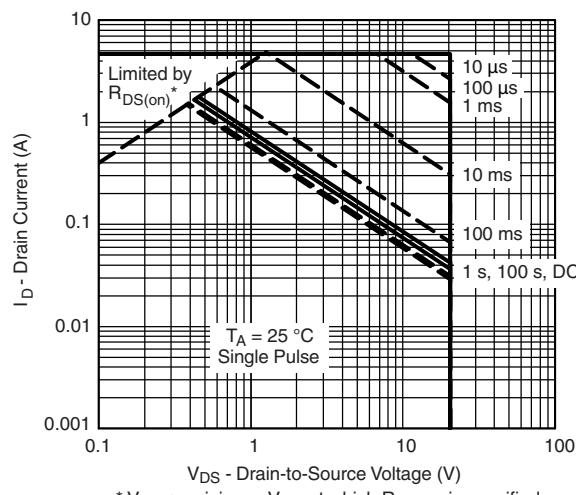
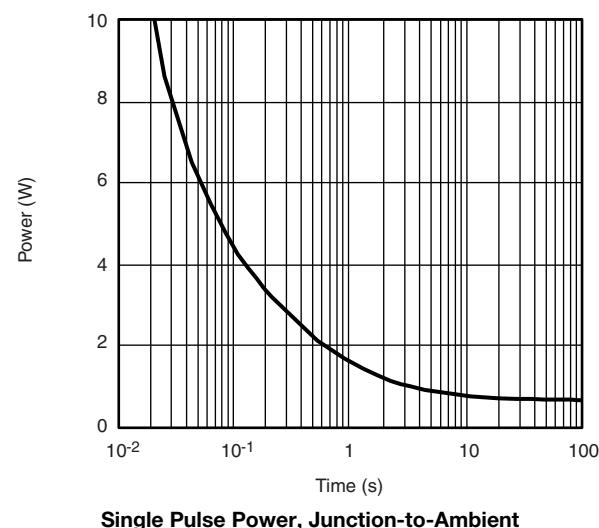
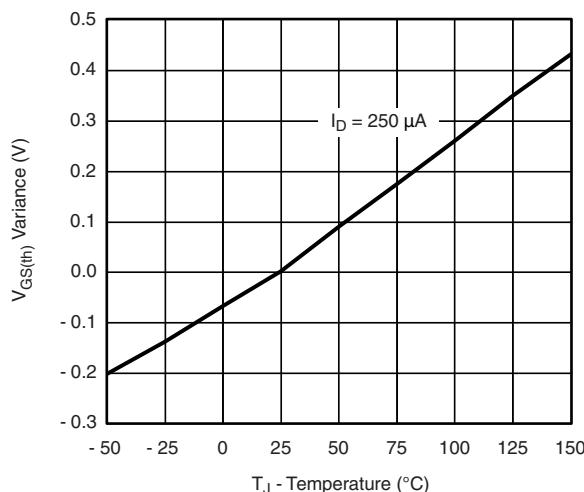
Notes

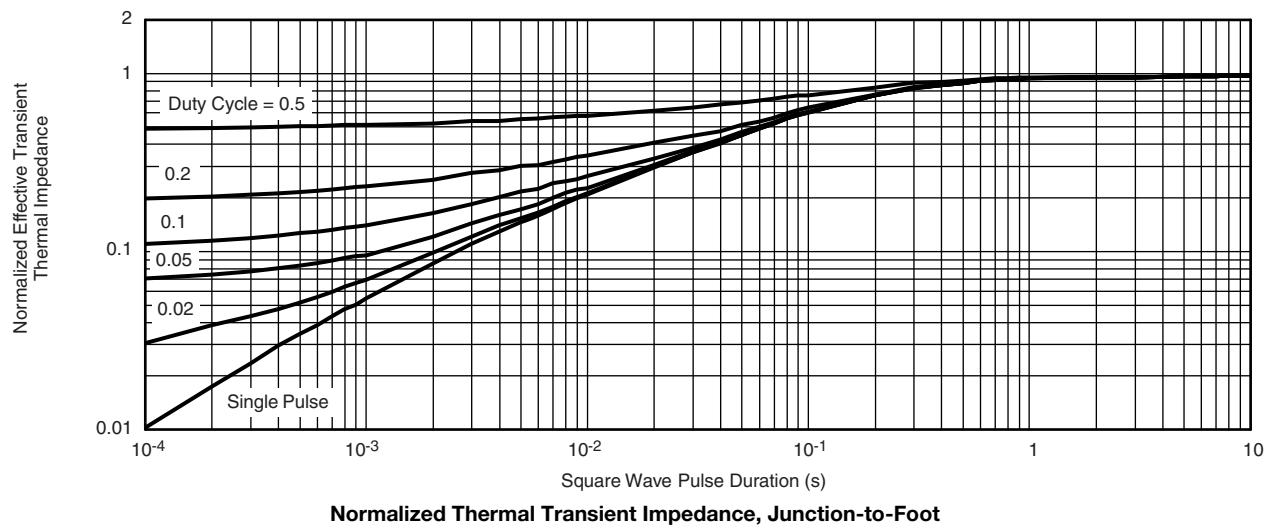
- a. Pulse test; pulse width $\leq 300 \mu\text{s}$, duty cycle $\leq 2 \%$
- b. Guaranteed by design, not subject to production testing

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

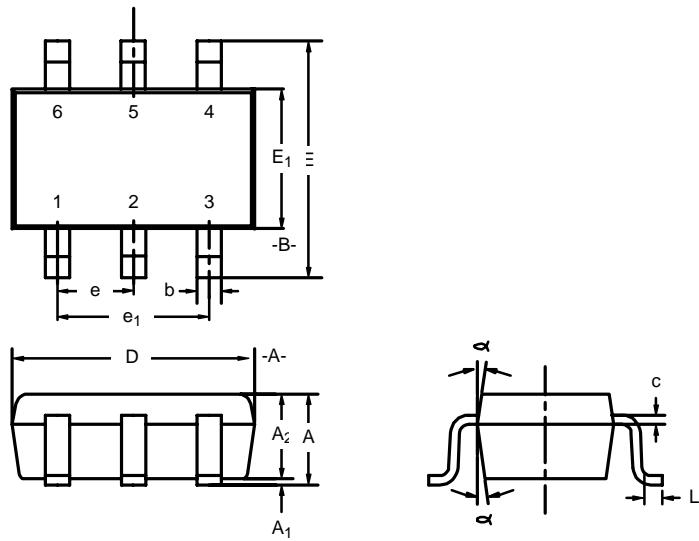
TYPICAL CHARACTERISTICS (25°C , unless otherwise noted)


TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

On-Resistance vs. Drain Current

Capacitance

Gate Charge

On-Resistance vs. Junction Temperature

Source-Drain Diode Forward Voltage

On-Resistance vs. Gate-to-Source Voltage

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)


TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)


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SC-70: 6-LEADS


Dim	MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max
A	0.90	—	1.10	0.035	—	0.043
A₁	—	—	0.10	—	—	0.004
A₂	0.80	—	1.00	0.031	—	0.039
b	0.15	—	0.30	0.006	—	0.012
c	0.10	—	0.25	0.004	—	0.010
D	1.80	2.00	2.20	0.071	0.079	0.087
E	1.80	2.10	2.40	0.071	0.083	0.094
E₁	1.15	1.25	1.35	0.045	0.049	0.053
e	0.65BSC			0.026BSC		
e₁	1.20	1.30	1.40	0.047	0.051	0.055
L	0.10	0.20	0.30	0.004	0.008	0.012
α	7°Nom			7°Nom		

ECN: S-03946—Rev. B, 09-Jul-01
DWG: 5550

Single-Channel LITTLE FOOT® SC-70 3-Pin and 6-Pin MOSFET Recommended Pad Pattern and Thermal Performance

INTRODUCTION

This technical note discusses pin-outs, package outlines, pad patterns, evaluation board layout, and thermal performance for single-channel LITTLE FOOT power MOSFETs in the SC-70 package. These new Vishay Siliconix devices are intended for small-signal applications where a miniaturized package is needed and low levels of current (around 350 mA) need to be switched, either directly or by using a level shift configuration. Vishay provides these single devices with a range of on-resistance specifications and in both traditional 3-pin and new 6-pin versions. The new 6-pin SC-70 package enables improved on-resistance values and enhanced thermal performance compared to the 3-pin package.

PIN-OUT

Figure 1 shows the pin-out description and Pin 1 identification for the single-channel SC-70 device in both 3-pin and 6-pin configurations. The pin-out of the 6-pin device allows the use of four pins as drain leads, which helps to reduce on-resistance and junction-to-ambient thermal resistance.

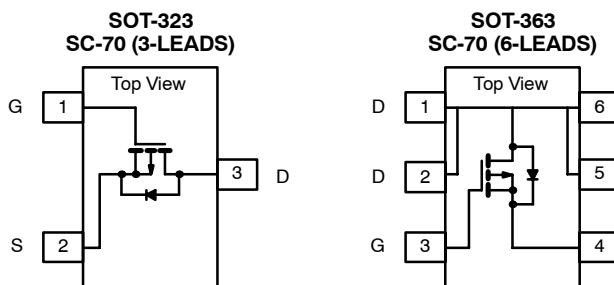


FIGURE 1.

For package dimensions see outline drawings:

SC-70 (3-Leads) (<http://www.vishay.com/doc?71153>)
 SC-70 (6-Leads) (<http://www.vishay.com/doc?71154>)

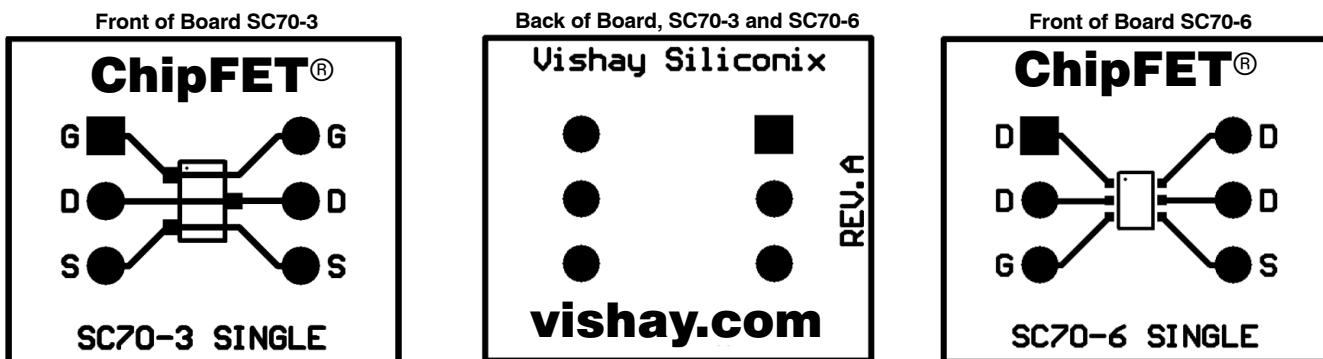


FIGURE 2.

THERMAL PERFORMANCE

Junction-to-Foot Thermal Resistance (the Package Performance)

Thermal performance for the 3-pin SC-70 measured as junction-to-foot thermal resistance is 285°C/W typical, 340°C/W maximum. Junction-to-foot thermal resistance for the 6-pin SC70-6 is 105°C/W typical, 130°C/W maximum — a nearly two-thirds reduction compared with the 3-pin device. The “foot” is the drain lead of the device as it connects with the body. This improved performance is obtained by the increase in drain leads from one to four on the 6-pin SC-70. Note that these numbers are somewhat higher than other LITTLE FOOT devices due to the limited thermal performance of the Alloy 42 lead-frame compared with a standard copper lead-frame.

Junction-to-Ambient Thermal Resistance (dependent on PCB size)

The typical R_{JA} for the single 3-pin SC-70 is 360°C/W steady state, compared with 180°C/W for the 6-pin SC-70. Maximum ratings are 430°C/W for the 3-pin device versus 220°C/W for the 6-pin device. All figures are based on the 1-inch square FR4 test board. The following table shows how the thermal resistance impacts power dissipation for the two different pin-outs at two different ambient temperatures.

SC-70 (3-PIN)	
Room Ambient 25 °C	Elevated Ambient 60 °C
$P_D = \frac{T_{J(max)} - T_A}{R_{JA}}$	$P_D = \frac{T_{J(max)} - T_A}{R_{JA}}$
$P_D = \frac{150^\circ\text{C} - 25^\circ\text{C}}{360^\circ\text{C}/\text{W}}$	$P_D = \frac{150^\circ\text{C} - 60^\circ\text{C}}{360^\circ\text{C}/\text{W}}$
$P_D = 347 \text{ mW}$	$P_D = 250 \text{ mW}$

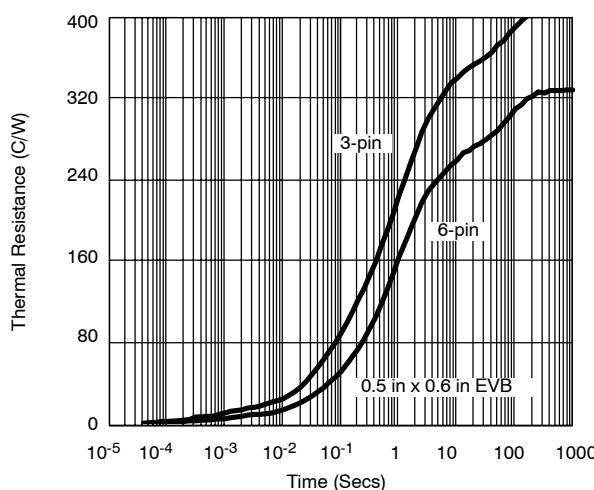


FIGURE 3. Comparison of SC70-3 and SC70-6 on EVB

SC-70 (6-PIN)

Room Ambient 25 °C	Elevated Ambient 60 °C
$P_D = \frac{T_{J(max)} - T_A}{R_{JA}}$	$P_D = \frac{T_{J(max)} - T_A}{R_{JA}}$
$P_D = \frac{150^\circ\text{C} - 25^\circ\text{C}}{180^\circ\text{C}/\text{W}}$	$P_D = \frac{150^\circ\text{C} - 60^\circ\text{C}}{180^\circ\text{C}/\text{W}}$
$P_D = 694 \text{ mW}$	$P_D = 500 \text{ mW}$

NOTE: Although they are intended for low-power applications, devices in the 6-pin SC-70 will handle power dissipation in excess of 0.5 W.

Testing

To aid comparison further, Figures 3 and 4 illustrate single-channel SC-70 thermal performance on two different board sizes and two different pad patterns. The results display the thermal performance out to steady state and produce a graphic account of the thermal performance variation between the two packages. The measured steady state values of R_{JA} for the single 3-pin and 6-pin SC-70 are as follows:

LITTLE FOOT SC-70		
	3-Pin	6-Pin
1) Minimum recommended pad pattern (see Figure 4) on the EVB.	410.31°C/W	329.7°C/W
2) Industry standard 1" square PCB with maximum copper both sides.	360°C/W	211.8°C/W

The results show that designers can reduce thermal resistance R_{JA} on the order of 20% simply by using the 6-pin device rather than the 3-pin device. In this example, a 80°C/W reduction was achieved without an increase in board area. If increasing board size is an option, a further 118°C/W reduction could be obtained by utilizing a 1-inch square PCB area.

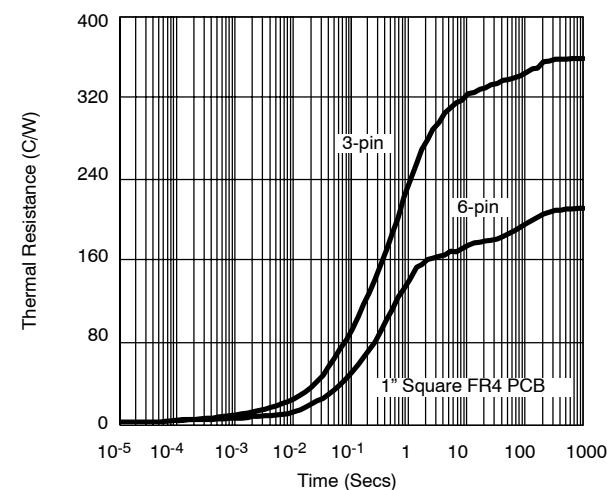
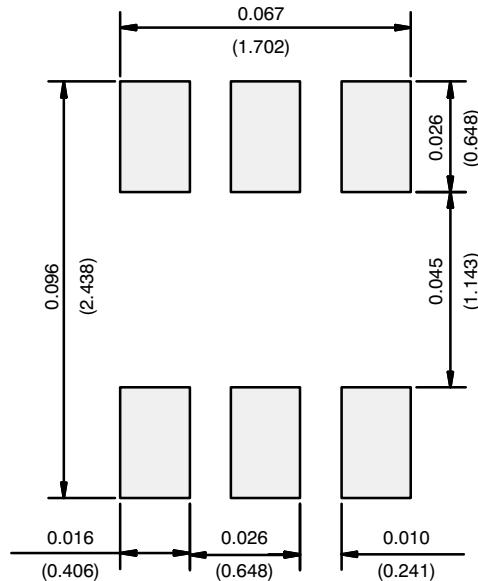


FIGURE 4. Comparison of SC70-3 and SC70-6 on 1" Square FR4 PCB

RECOMMENDED MINIMUM PADS FOR SC-70: 6-Lead



Recommended Minimum Pads
Dimensions in Inches/(mm)

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